

S1237

SILICON PNP TRIPLE DIFFUSED TYPE (PCT PROCESS)

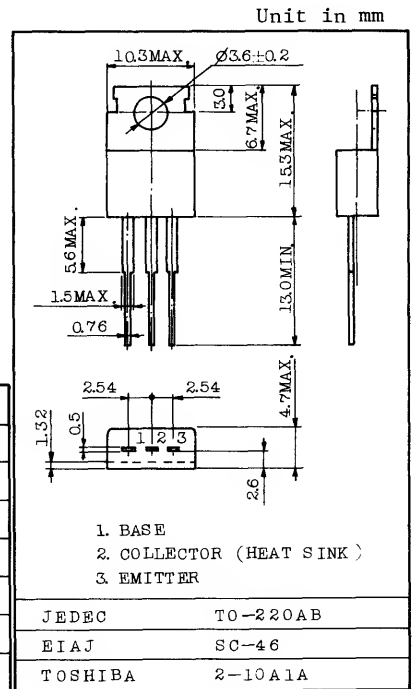
POWER AMPLIFIER APPLICATIONS.
TV VERTICAL OUTPUT APPLICATIONS.

FEATURES:

- . Good Linearity of h_{FE}
- . Complementary to S1236

MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CB0}	-90	V
Collector-Emitter Voltage	V_{CE0}	-90	V
Emitter-Base Voltage	V_{EB0}	-5	V
Collector Current	I_C	-4	A
Emitter Current	I_E	4	A
Base Current	I_B	-3	A
Collector Power Dissipation ($T_c=25^{\circ}\text{C}$)	P_C	40	W
Junction Temperature	T_j	150	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	-55 ~ 150	$^{\circ}\text{C}$

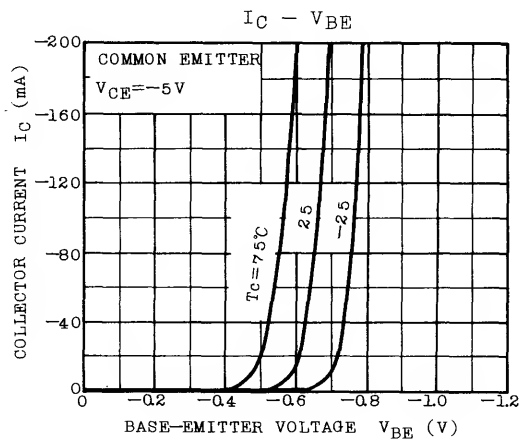
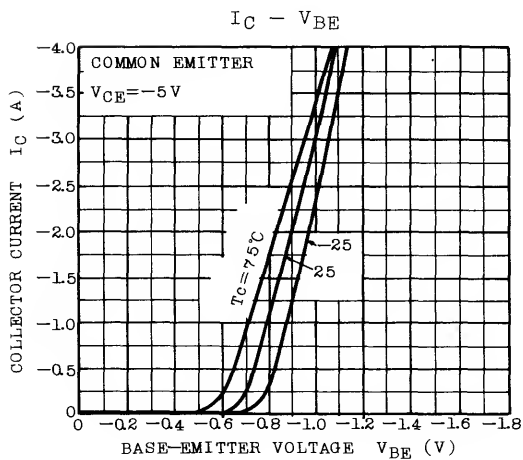
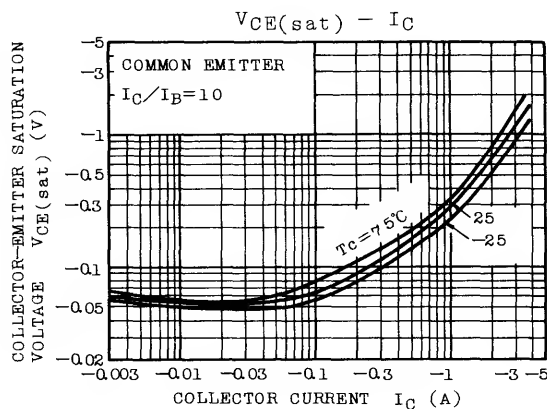
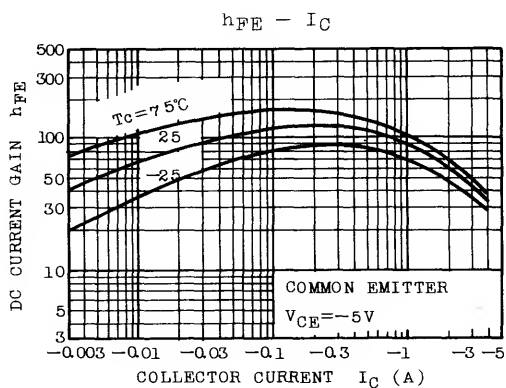
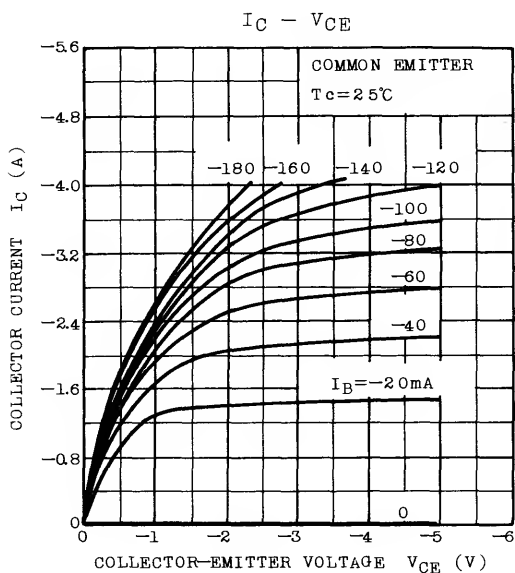


Mounting Kit No. AC75

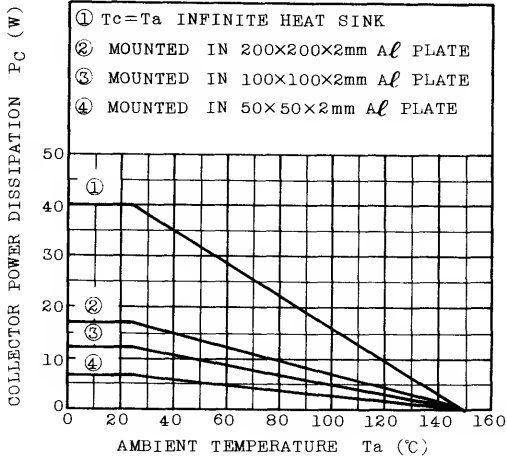
Weight : 1.9g

ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=-90\text{V}, I_E=0$	-	-	-20	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=-5\text{V}, I_C=0$	-	-	-10	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CE0}$	$I_C=-50\text{mA}, I_B=0$	-90	-	-	V
DC Current Gain	$h_{FE(1)}$	$V_{CE}=-5\text{V}, I_C=-0.5\text{A}$	40	-	200	
	$h_{FE(2)}$	$V_{CE}=-5\text{V}, I_C=-3\text{A}$	15	-	-	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-3\text{A}, I_B=-0.3\text{A}$	-	-	-1.7	V
Base-Emitter Voltage	V_{BE}	$V_{CE}=-5\text{V}, I_C=-3\text{A}$	-	-	-1.5	V
Transition Frequency	f_T	$V_{CE}=-5\text{V}, I_C=-0.5\text{A}$	3	5	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=-10\text{V}, I_E=0, f=1\text{MHz}$	-	130	-	pF



$P_C - T_a$



SAFE OPERATING AREA

